Docket No.: 67161-077 PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Yasushi NAKASHIMA, et al.

Serial No.: : Group Art Unit:

Filed: July 25, 2003 : Examiner:

For: SEMICONDUCTOR MEMORY DEVICE

INFORMATION DISCLOSURE STATEMENT

Mail Stop Patent Application Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

The relevance of each non-English language reference is discussed in the present specification.

Serial No.:

Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

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Date: July 25, 2003

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				APPLICANT Yasushi NAKASH	APPLICANT Yasushi NAKASHIMA, et al.						
(PTO-1449)					FILING DATE July 25, 2003						
				U.S. PATE	NT DOCUMENTS						
EXAMINER'S Document Number Publication Date Name of Patentee or Applicant of Cited Pages, Columns, Line										ines Where	
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			JP 62-257698	11/10/1987	TANAKA, et al.				abstract		
			JP 7-161840	06/23/1995	SASAKI				abstract		
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EXAMINER'S INITIALS											
NAIKI, et al. "Center Wordline Cell: A New Symmetric Layout Cell for 64Mb SRAM" International Electron Devices Meeting Technical Digest, Washington, D.C. (December 5-8, 1993) pp. 33.3.1-33.3.4.										19	
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.